NSN 5961-01-467-6952

Diode Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-467-6952 **Inclosure Material:** Glass **Overall Length:** 0.120 millimeters **Overall Height:** 0.051 millimeters **Overall Width:** 0.120 millimeters **Mounting Facility Quantity: Mounting Method: Terminal Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 13.3 working peak reverse voltage **Current Rating Per Characteristic:** 12.00 amperes source cutoff current universal **Power Rating Per Characteristic:** 300.0 watts small-signal input power, common-emitter absolute **Maximum Operating Tempurature Per Measurement Point:** -55.0 degrees celsius case and 150.0 degrees celsius case **Special Features:** Diode-power array **Terminal Type And Quantity:** 6 uninsulated wire lead Shelf Life: N/a **Unit Of Measure: Demilitarization:**

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